

# MMBT3906L, SMMBT3906L

## General Purpose Transistor

### PNP Silicon

#### Features

- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

#### MAXIMUM RATINGS

| Rating                            | Symbol    | Value | Unit |
|-----------------------------------|-----------|-------|------|
| Collector – Emitter Voltage       | $V_{CEO}$ | -40   | Vdc  |
| Collector – Base Voltage          | $V_{CBO}$ | -40   | Vdc  |
| Emitter – Base Voltage            | $V_{EBO}$ | -5.0  | Vdc  |
| Collector Current – Continuous    | $I_C$     | -200  | mAdc |
| Collector Current – Peak (Note 3) | $I_{CM}$  | -800  | mAdc |

#### THERMAL CHARACTERISTICS

| Characteristic                                                                                                        | Symbol          | Max         | Unit                       |
|-----------------------------------------------------------------------------------------------------------------------|-----------------|-------------|----------------------------|
| Total Device Dissipation FR-5 Board<br>(Note 1) @ $T_A = 25^\circ\text{C}$<br>Derate above $25^\circ\text{C}$         | $P_D$           | 225<br>1.8  | mW<br>mW/ $^\circ\text{C}$ |
| Thermal Resistance, Junction-to-Ambient                                                                               | $R_{\theta JA}$ | 556         | $^\circ\text{C}/\text{W}$  |
| Total Device Dissipation Alumina<br>Substrate, (Note 2) @ $T_A = 25^\circ\text{C}$<br>Derate above $25^\circ\text{C}$ | $P_D$           | 300<br>2.4  | mW<br>mW/ $^\circ\text{C}$ |
| Thermal Resistance, Junction-to-Ambient                                                                               | $R_{\theta JA}$ | 417         | $^\circ\text{C}/\text{W}$  |
| Junction and Storage Temperature                                                                                      | $T_J, T_{stg}$  | -55 to +150 | $^\circ\text{C}$           |

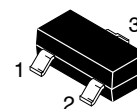
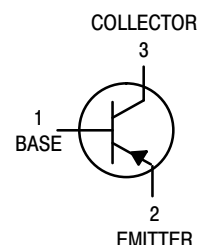
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. FR-5 =  $1.0 \times 0.75 \times 0.062$  in.
2. Alumina =  $0.4 \times 0.3 \times 0.024$  in. 99.5% alumina.
3. Reference SOA curve.



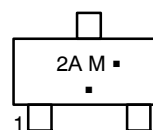
ON Semiconductor®

<http://onsemi.com>



SOT-23 (TO-236)  
CASE 318  
STYLE 6

#### MARKING DIAGRAM



2A = Specific Device Code  
M = Date Code\*  
▪ = Pb-Free Package

(Note: Microdot may be in either location)

\*Date Code orientation and/or overbar may vary depending upon manufacturing location.

#### ORDERING INFORMATION

| Device        | Package             | Shipping†            |
|---------------|---------------------|----------------------|
| MMBT3906LT1G  | SOT-23<br>(Pb-Free) | 3,000 / Tape & Reel  |
| MMBT3906LT3G  | SOT-23<br>(Pb-Free) | 10,000 / Tape & Reel |
| SMMBT3906LT1G | SOT-23<br>(Pb-Free) | 3,000 / Tape & Reel  |
| SMMBT3906LT3G | SOT-23<br>(Pb-Free) | 10,000 / Tape & Reel |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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## ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

| Characteristic                                                                         | Symbol        | Min  | Max | Unit |
|----------------------------------------------------------------------------------------|---------------|------|-----|------|
| <b>OFF CHARACTERISTICS</b>                                                             |               |      |     |      |
| Collector – Emitter Breakdown Voltage<br>( $I_C = -1.0\text{ mA}$ , $I_B = 0$ )        | $V_{(BR)CEO}$ | -40  | –   | Vdc  |
| Collector – Base Breakdown Voltage<br>( $I_C = -10\text{ }\mu\text{A}$ , $I_E = 0$ )   | $V_{(BR)CBO}$ | -40  | –   | Vdc  |
| Emitter – Base Breakdown Voltage<br>( $I_E = -10\text{ }\mu\text{A}$ , $I_C = 0$ )     | $V_{(BR)EBO}$ | -5.0 | –   | Vdc  |
| Base Cutoff Current<br>( $V_{CE} = -30\text{ Vdc}$ , $V_{EB} = -3.0\text{ Vdc}$ )      | $I_{BL}$      | –    | -50 | nAdc |
| Collector Cutoff Current<br>( $V_{CE} = -30\text{ Vdc}$ , $V_{EB} = -3.0\text{ Vdc}$ ) | $I_{CEX}$     | –    | -50 | nAdc |

## ON CHARACTERISTICS (Note 4)

|                                                                                                                                                                                                                                                                                                                      |               |                             |                         |     |
|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|---------------|-----------------------------|-------------------------|-----|
| DC Current Gain<br>( $I_C = -0.1\text{ mA}$ , $V_{CE} = -1.0\text{ Vdc}$ )<br>( $I_C = -1.0\text{ mA}$ , $V_{CE} = -1.0\text{ Vdc}$ )<br>( $I_C = -10\text{ mA}$ , $V_{CE} = -1.0\text{ Vdc}$ )<br>( $I_C = -50\text{ mA}$ , $V_{CE} = -1.0\text{ Vdc}$ )<br>( $I_C = -100\text{ mA}$ , $V_{CE} = -1.0\text{ Vdc}$ ) | $H_{FE}$      | 60<br>80<br>100<br>60<br>30 | –<br>–<br>300<br>–<br>– | –   |
| Collector – Emitter Saturation Voltage<br>( $I_C = -10\text{ mA}$ , $I_B = -1.0\text{ mA}$ )<br>( $I_C = -50\text{ mA}$ , $I_B = -5.0\text{ mA}$ )                                                                                                                                                                   | $V_{CE(sat)}$ | –<br>–                      | -0.25<br>-0.4           | Vdc |
| Base – Emitter Saturation Voltage<br>( $I_C = -10\text{ mA}$ , $I_B = -1.0\text{ mA}$ )<br>( $I_C = -50\text{ mA}$ , $I_B = -5.0\text{ mA}$ )                                                                                                                                                                        | $V_{BE(sat)}$ | -0.65<br>–                  | -0.85<br>-0.95          | Vdc |

## SMALL-SIGNAL CHARACTERISTICS

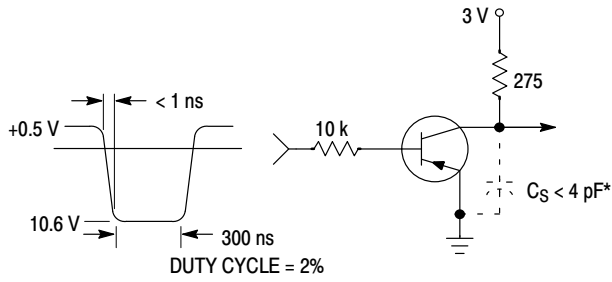
|                                                                                                                                      |           |     |     |                  |
|--------------------------------------------------------------------------------------------------------------------------------------|-----------|-----|-----|------------------|
| Current – Gain – Bandwidth Product<br>( $I_C = -10\text{ mA}$ , $V_{CE} = -20\text{ Vdc}$ , $f = 100\text{ MHz}$ )                   | $f_T$     | 250 | –   | MHz              |
| Output Capacitance<br>( $V_{CB} = -5.0\text{ Vdc}$ , $I_E = 0$ , $f = 1.0\text{ MHz}$ )                                              | $C_{obo}$ | –   | 4.5 | pF               |
| Input Capacitance<br>( $V_{EB} = -0.5\text{ Vdc}$ , $I_C = 0$ , $f = 1.0\text{ MHz}$ )                                               | $C_{ibo}$ | –   | 10  | pF               |
| Input Impedance<br>( $I_C = -1.0\text{ mA}$ , $V_{CE} = -10\text{ Vdc}$ , $f = 1.0\text{ kHz}$ )                                     | $h_{ie}$  | 2.0 | 12  | k $\Omega$       |
| Voltage Feedback Ratio<br>( $I_C = -1.0\text{ mA}$ , $V_{CE} = -10\text{ Vdc}$ , $f = 1.0\text{ kHz}$ )                              | $h_{re}$  | 0.1 | 10  | $\times 10^{-4}$ |
| Small – Signal Current Gain<br>( $I_C = -1.0\text{ mA}$ , $V_{CE} = -10\text{ Vdc}$ , $f = 1.0\text{ kHz}$ )                         | $h_{fe}$  | 100 | 400 | –                |
| Output Admittance<br>( $I_C = -1.0\text{ mA}$ , $V_{CE} = -10\text{ Vdc}$ , $f = 1.0\text{ kHz}$ )                                   | $h_{oe}$  | 3.0 | 60  | $\mu\text{mhos}$ |
| Noise Figure<br>( $I_C = -100\text{ }\mu\text{A}$ , $V_{CE} = -5.0\text{ Vdc}$ , $R_S = 1.0\text{ k}\Omega$ , $f = 1.0\text{ kHz}$ ) | NF        | –   | 4.0 | dB               |

## SWITCHING CHARACTERISTICS

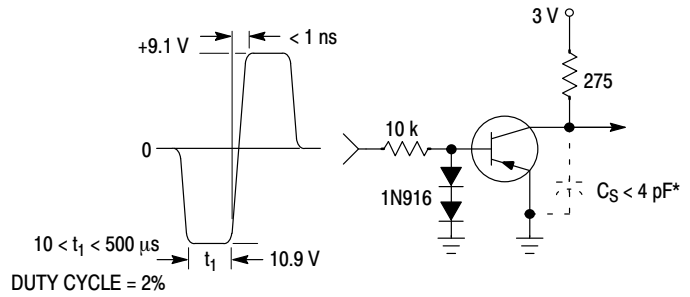
|              |                                                                                                                |                |   |     |    |
|--------------|----------------------------------------------------------------------------------------------------------------|----------------|---|-----|----|
| Delay Time   | (V <sub>CC</sub> = -3.0 Vdc, V <sub>BE</sub> = 0.5 Vdc,<br>I <sub>C</sub> = -10 mA, I <sub>B1</sub> = -1.0 mA) | t <sub>d</sub> | – | 35  | ns |
| Rise Time    |                                                                                                                | t <sub>r</sub> | – | 35  |    |
| Storage Time | (V <sub>CC</sub> = -3.0 Vdc, I <sub>C</sub> = -10 mA,<br>I <sub>B1</sub> = I <sub>B2</sub> = -1.0 mA)          | t <sub>s</sub> | – | 225 | ns |
| Fall Time    |                                                                                                                | t <sub>f</sub> | – | 75  |    |

4. Pulse Test: Pulse Width  $\leq 300\text{ }\mu\text{s}$ , Duty Cycle  $\leq 2.0\%$ .

# MMBT3906L, SMMBT3906L



**Figure 1. Delay and Rise Time  
Equivalent Test Circuit**

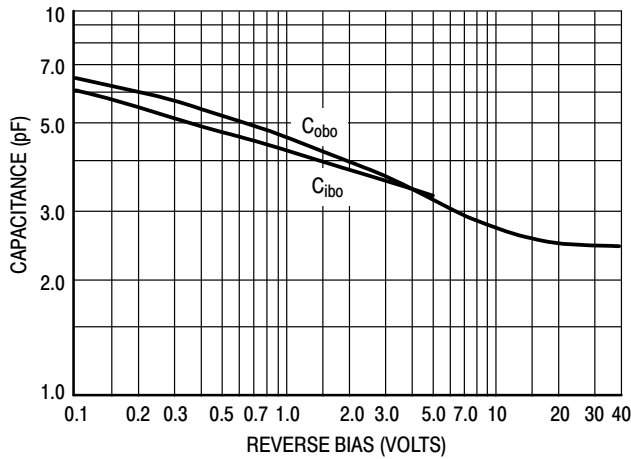


**Figure 2. Storage and Fall Time  
Equivalent Test Circuit**

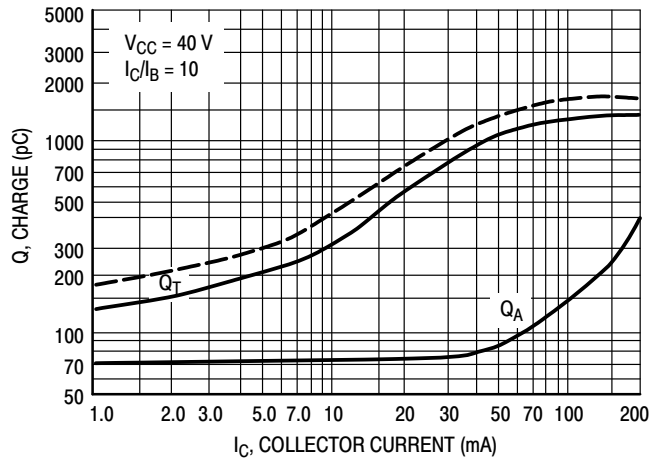
\* Total shunt capacitance of test jig and connectors

## TYPICAL TRANSIENT CHARACTERISTICS

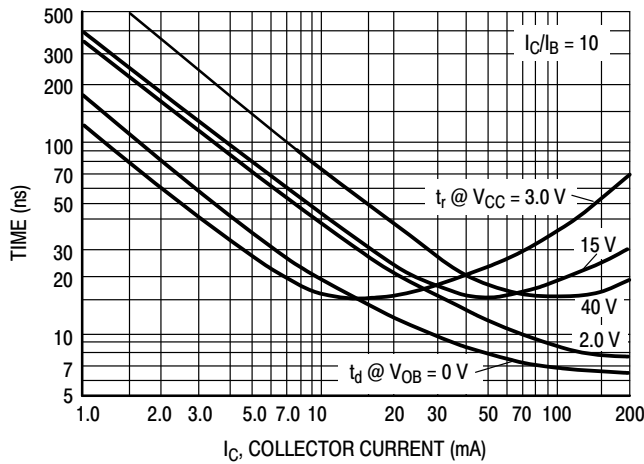
—  $T_J = 25^\circ\text{C}$   
 - -  $T_J = 125^\circ\text{C}$



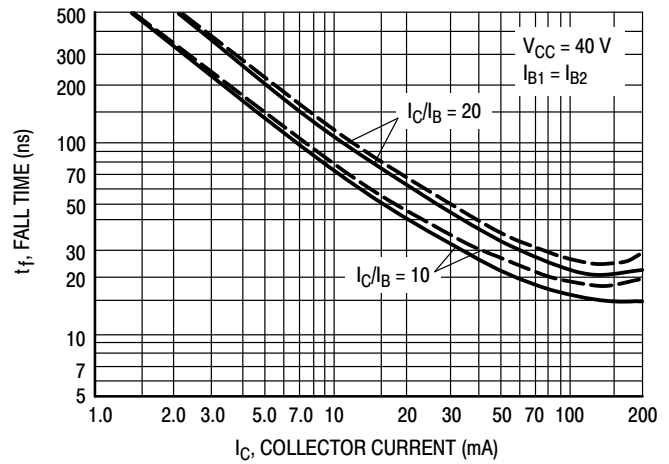
**Figure 3. Capacitance**



**Figure 4. Charge Data**



**Figure 5. Turn-On Time**



**Figure 6. Fall Time**

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## TYPICAL AUDIO SMALL-SIGNAL CHARACTERISTICS NOISE FIGURE VARIATIONS

( $V_{CE} = -5.0$  Vdc,  $T_A = 25^\circ\text{C}$ , Bandwidth = 1.0 Hz)

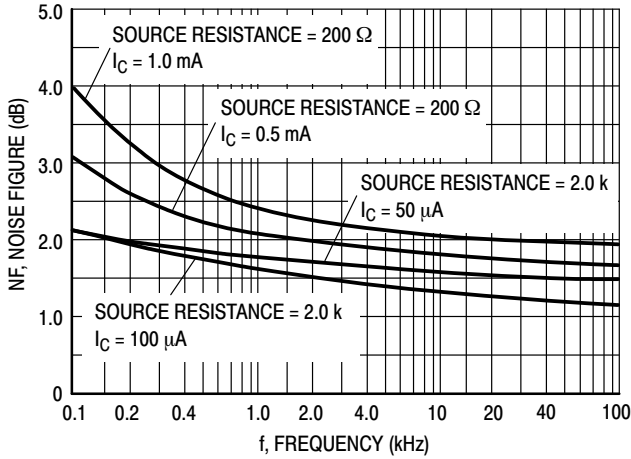


Figure 7.

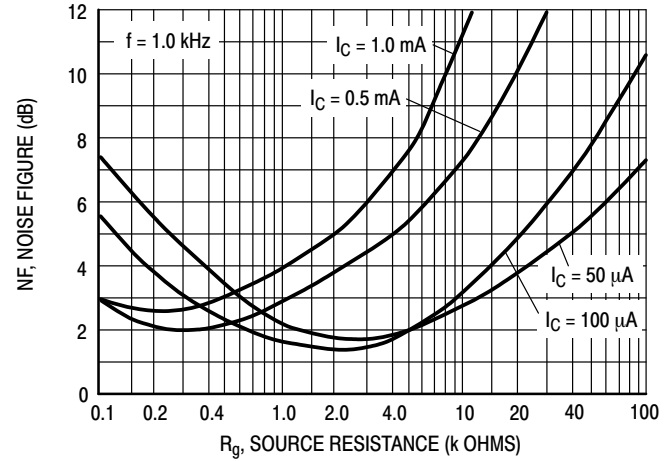


Figure 8.

## h PARAMETERS

( $V_{CE} = -10$  Vdc,  $f = 1.0$  kHz,  $T_A = 25^\circ\text{C}$ )

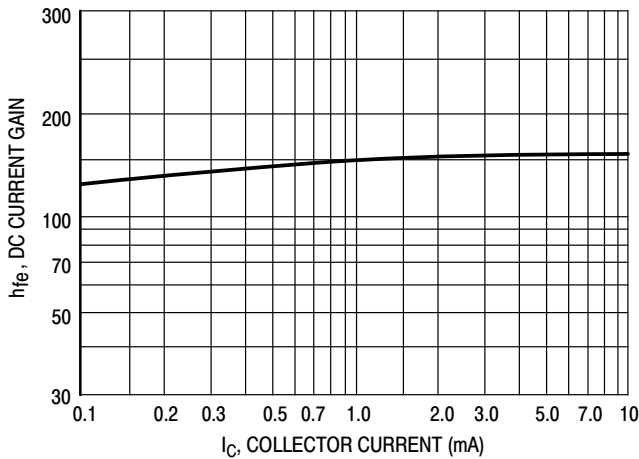


Figure 9. Current Gain

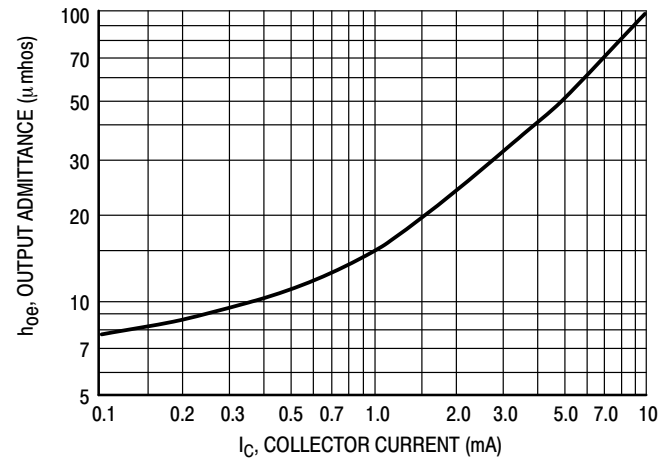


Figure 10. Output Admittance

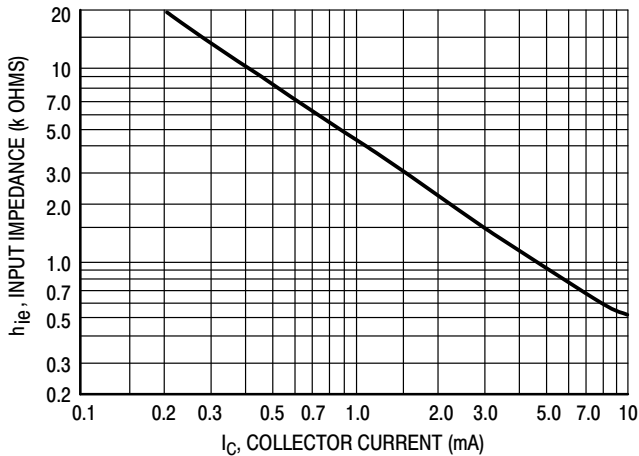


Figure 11. Input Impedance

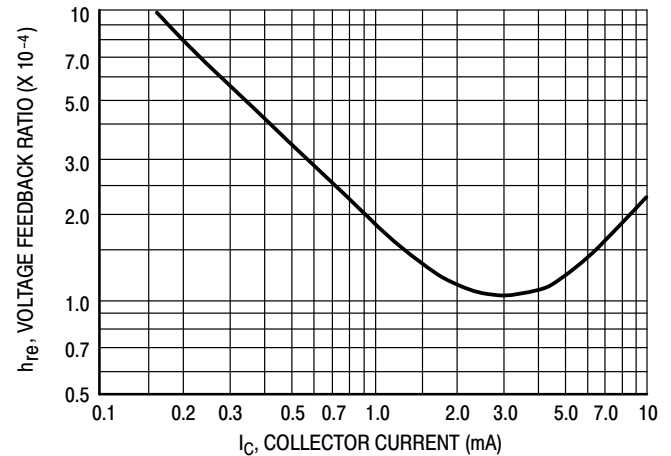


Figure 12. Voltage Feedback Ratio

# MMBT3906L, SMMBT3906L

## TYPICAL STATIC CHARACTERISTICS

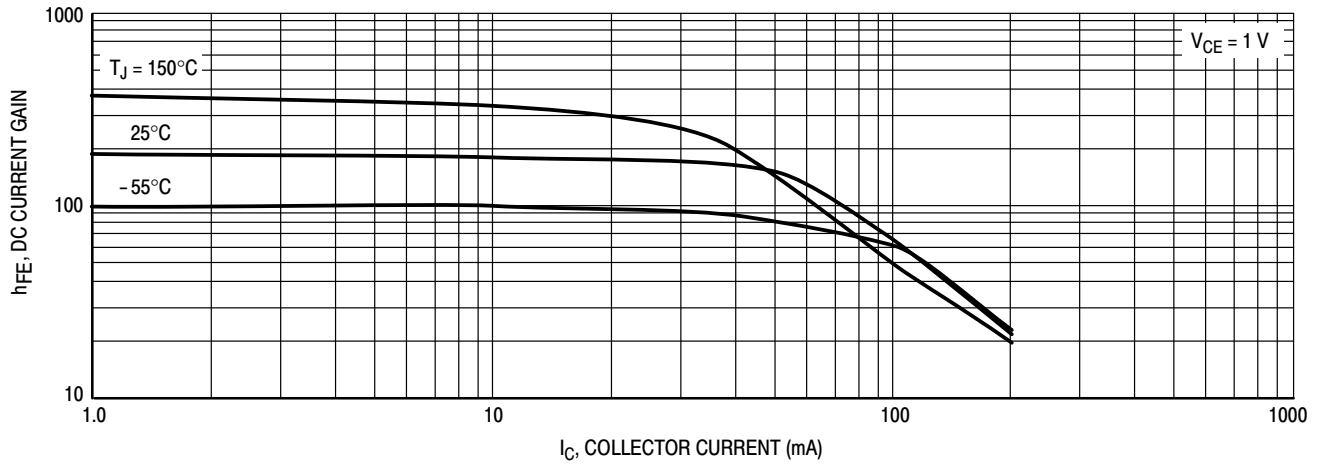


Figure 13. DC Current Gain

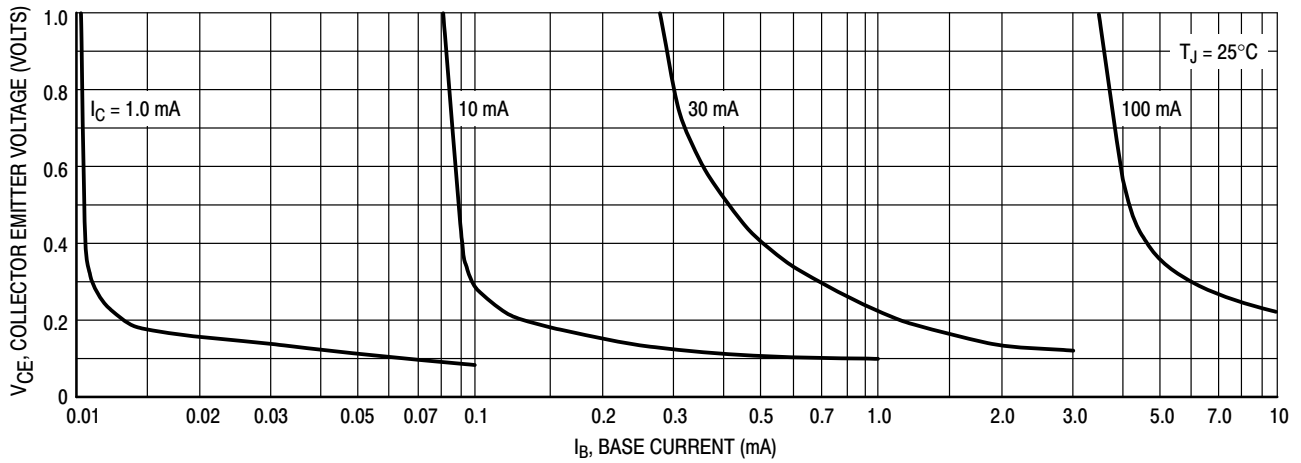
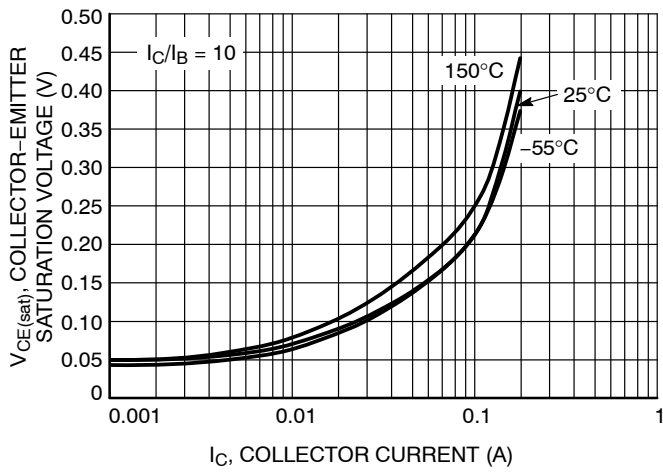
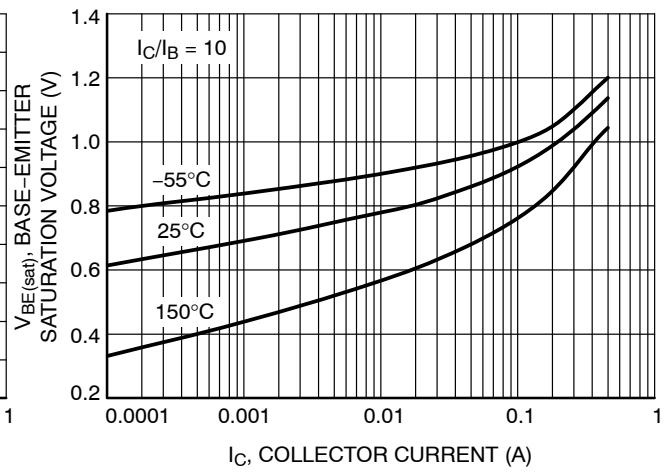


Figure 14. Collector Saturation Region

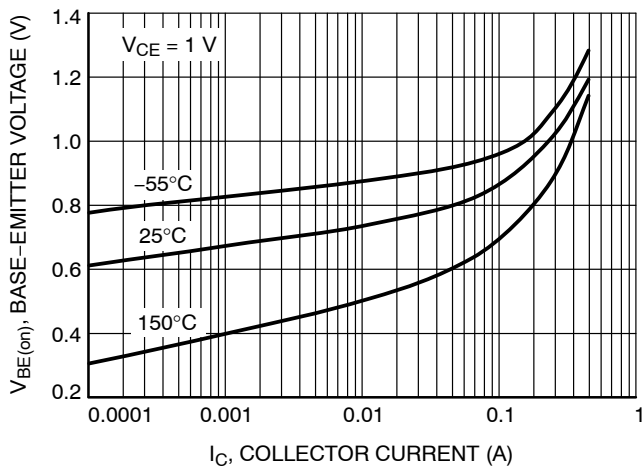
# MMBT3906L, SMMBT3906L



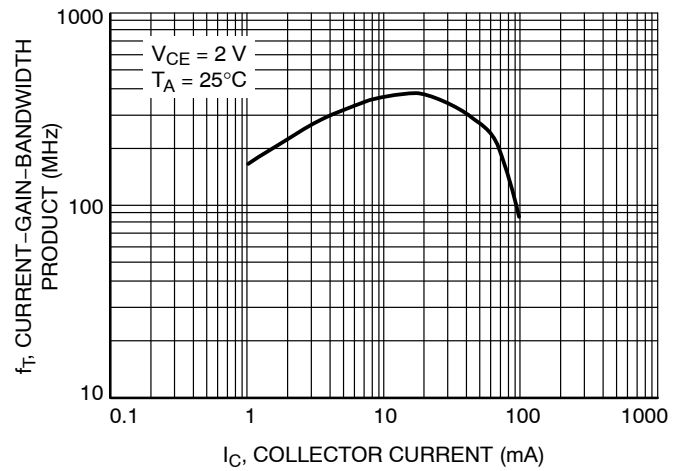
**Figure 15. Collector Emitter Saturation Voltage vs. Collector Current**



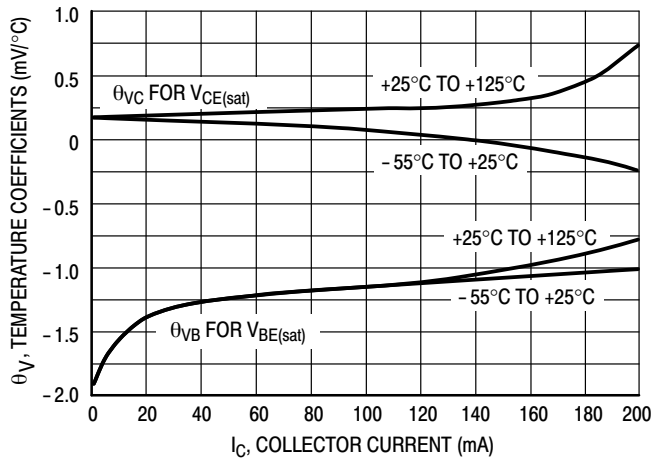
**Figure 16. Base Emitter Saturation Voltage vs. Collector Current**



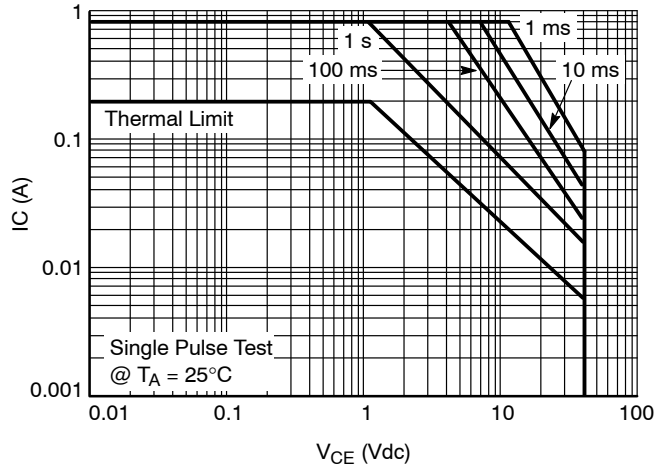
**Figure 17. Base Emitter Voltage vs. Collector Current**



**Figure 18. Current Gain Bandwidth vs. Collector Current**



**Figure 19. Temperature Coefficients**

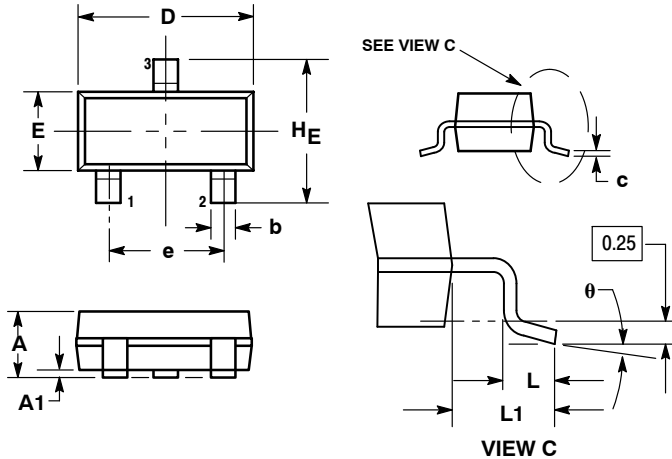


**Figure 20. Safe Operating Area**

# MMBT3906L, SMMBT3906L

## PACKAGE DIMENSIONS

SOT-23 (TO-236)  
CASE 318-08  
ISSUE AP



### NOTES:

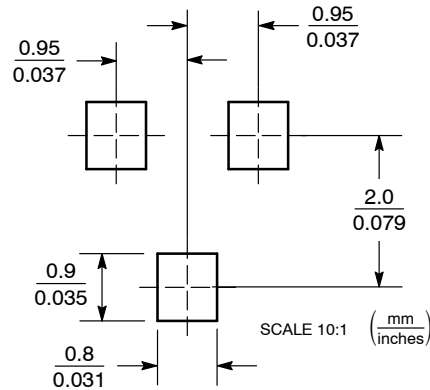
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

| DIM | MILLIMETERS |      |      | INCHES |       |       |
|-----|-------------|------|------|--------|-------|-------|
|     | MIN         | NOM  | MAX  | MIN    | NOM   | MAX   |
| A   | 0.89        | 1.00 | 1.11 | 0.035  | 0.040 | 0.044 |
| A1  | 0.01        | 0.06 | 0.10 | 0.001  | 0.002 | 0.004 |
| b   | 0.37        | 0.44 | 0.50 | 0.015  | 0.018 | 0.020 |
| c   | 0.09        | 0.13 | 0.18 | 0.003  | 0.005 | 0.007 |
| D   | 2.80        | 2.90 | 3.04 | 0.110  | 0.114 | 0.120 |
| E   | 1.20        | 1.30 | 1.40 | 0.047  | 0.051 | 0.055 |
| e   | 1.78        | 1.90 | 2.04 | 0.070  | 0.075 | 0.081 |
| L   | 0.10        | 0.20 | 0.30 | 0.004  | 0.008 | 0.012 |
| L1  | 0.35        | 0.54 | 0.69 | 0.014  | 0.021 | 0.029 |
| HE  | 2.10        | 2.40 | 2.64 | 0.083  | 0.094 | 0.104 |
| θ   | 0°          | ---  | 10°  | 0°     | ---   | 10°   |

### STYLE 6:

- PIN 1. BASE
- EMITTER
- COLLECTOR

## SOLDERING FOOTPRINT\*



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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